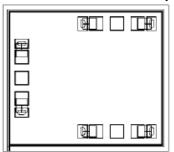
AMT1804-3 18 – 26GHz Power Divider Chip



Key Features:

Frequency range: 18 – 26GHz
Input/output standing wave: 1.2

Insertion loss: 0.5dBIsolation: 25dB

• Chip dimensions: 1.05mm x 1.2mm x 0.1mm

• Applications: wireless communication, transceiver module, radio telecommunication etc.

Description:

AMT1804-3 is a 1-to-2 power divider chip designed by Gallium Arsenide (GaAs) process, it covers 18 – 26GHz frequency range, with typical 25dB isolation. This chip is designed with ground through metal vias on the back technology.

Absolute Maximum Ratings (Ta = 25°C)

Symbol	Parameter	Value	Remark
Pin	Input Power	+37dBm	
Tch	Operating Temperature	150°C	
Tm	Sintering Temperature	310°C	30s, N ₂ protection
Tstg	Storage Temperature	-65 ~ +150°C	

^[1] Operation outside any of the Absolute Maximum Ratings may cause permanent device damage.

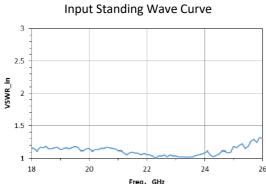
Electrical Characteristics (Ta = 25°C)

Symbol	Parameter	Test Conditions	Value		Unit	
			Min	Typical	Max	
VSWR_in	Input Standing Wave		1	1.2	1.4	
VSWR_out	Output Standing Wave	Pin = 0 dBm	-	1.2	1.4	
IL	Insertion Loss	F : 18 ~ 26GHz	-	0.5	0.8	dB
ISO	Isolation		20	25	-	dB

Typical Performance

18

20



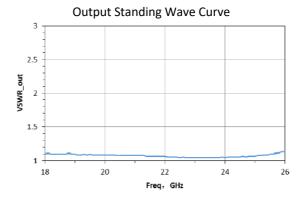


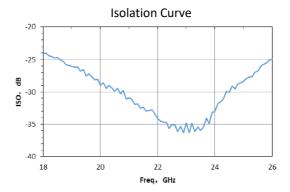
22

Freq, GHz

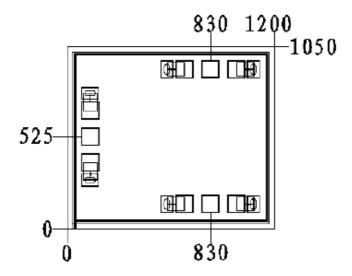
24

26

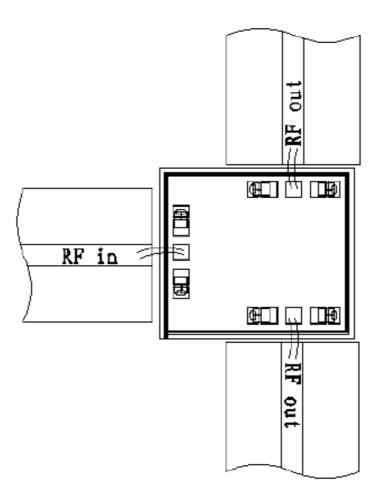




Chip Dimensions (Unit: μ m)



Chip Layout Diagram



Please see Appendix A for details.